

L Number	Hits	Search Text	DB	Time stamp
1	41267	"semiconductor memory" and "memory cell"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:35
2	97088	DRAM or (dynamic adj5 random adj5 access adj5 memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:04
3	13849	("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:04
4	6757	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:05
5	4822	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:05
6	4	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and sub\$1decoder and gap	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:07
7	1828	(DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:08
8	1259	((DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array") and transistor and well	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:09
9	21	((((DRAM or (dynamic adj5 random adj5 access adj5 memory)) and PMOS and NMOS and "memory cell array") and transistor and well) and sub\$1decoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:14
10	790	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$1decoder or pre\$1decoder)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:15
11	684	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$1decoder or pre\$1decoder) and 365/\$7.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:33
14	79	((("semiconductor memory" and "memory cell") and (DRAM or (dynamic adj5 random adj5 access adj5 memory))) and (sense adj3 amplifier)) and row and column and array) and (sub\$1decoder or pre\$1decoder) and 365/63.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:35
15	15711	"semiconductor memory" near5 "memory cell"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/07 16:35

16	819	("semiconductor memory" near5 "memory cell") near5 (DRAM or (dynamic adj5 random adj5 access adj5 memory))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:51
18	23	((("semiconductor memory" near5 "memory cell") near5 (DRAM or (dynamic adj5 random adj5 access adj5 memory))) near10 amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:52
19	23578	"memory cell" same row same column	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:38
20	2366	("memory cell" same row same column) same substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:39
22	67	((("memory cell" same row same column) same substrate) same amplifier same "memory array"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:47
23	2	((("memory cell" same row same column) same substrate) same amplifier same sub\$1decoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:55
24	450	"sense amplifier driver"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:53
28	9	"sense amplifier driver" and subdecoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:57
29	15	subdecoder near5 amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:56
30	283	"sense amplifier driver" and decoder	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:57
31	53	("sense amplifier driver" and decoder) and gap and row and column	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:58
32	53	((("sense amplifier driver" and decoder) and gap and row and column) and memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 16:58
34	41	((("sense amplifier driver" and decoder) and gap and row and column) and memory) and 365/\$7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 17:08
35	123	kawasaki-satoshi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 17:08

36	1	kawasaki-satoshi-\$.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/07 17:09
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